

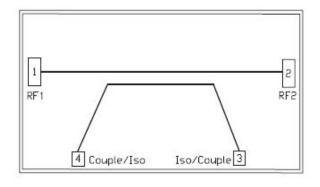
GaAs MMIC Monolithic Integrated Directional Coupler, 18-50GHz

Performance characteristics

• Frequency range: 18-50 GHz

- Insertion loss : 0.6 dB
- Coupling: 15dB
- Coupling flatness: 1.2dB
- VSWR: 1.2/1.2
- 500hm input / output
- 100% on-wafer testing
- Chip size: 1.52 x 0.97 x 0.1mm

Functional Block Diagram



Product Introduction

GDC-185015 single-chip coupler chip covers a frequency range of 18 GHz ~50 GHz, with a coupling degree of 15 dB. The chip has an insertion loss of 0.6 dB, a coupling flatness of 1.2 dB, and a port VSWR of 1.2 in the entire operating frequency band. The chip uses an on-chip through-hole metallization process to ensure good grounding, does not require additional grounding measures, and is simple and convenient to use.

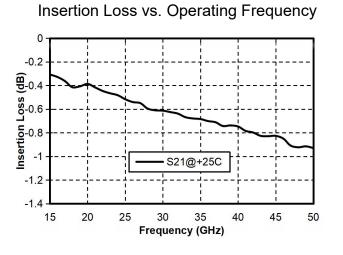
Use restriction parameter ¹		
Maximum input power	+40dBm	
Operating temperature	-55 ~ +85°C	
Storage temperature	-65 ~ +150°C	

[1] Exceeding any of these maximum limits may cause permanent damage.

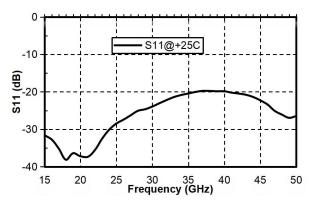
Electrical performance parameters (TA = +25°C)				
Index	Minimum	Typical Value	Maximum	Unit
Frequency Range	18-50			GHz
Insertion loss	-	0.6	-	dB
Coupling	-	15	-	dB
Input return loss	-	20	-	dB
Through output return loss	-	20	-	dB
Coupled output return loss	-	20	-	dB
Isolation		30		dB

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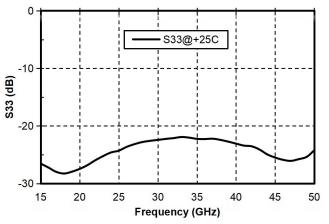
Main index test curve

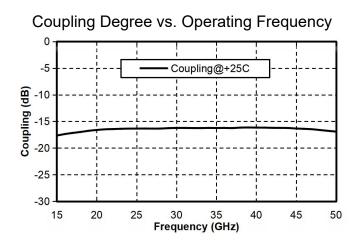


Thru Input Return Loss vs. Operating Frequency

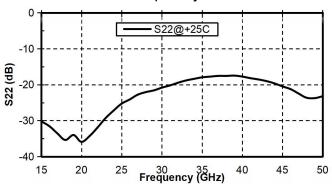


Coupled Output Return Loss vs. Operating Frequency

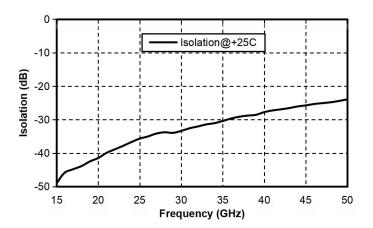




Through Output Return Loss vs. Operating Frequency



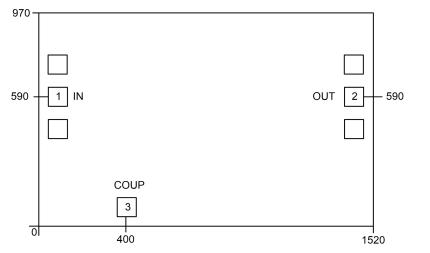
Isolation vs. Operating Frequency





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Appearance structure ²



[2] The units in the figure are all micrometers (dimensional tolerance: ± 50um.)

Bonding point definition

Bonding point	Function	Functional Description
number	Symbol	
1	RF IN	RF signal input terminal
2	RF OUT	Direct RF signal output
3	Coupling	Coupled RF signal output
Chip bottom	GND	The bottom of the chip needs to be well grounded to RF and DC

Recommended assembly drawing

